


POWER RECTIFIER DIODES

T-Modules

Features

- Electrically isolated base plate
- Types up to 1200 V_{RRM}
- 3500 V_{RMS} isolating voltage
- Simplified mechanical designs, rapid assembly
- High surge capability
- Large creepage distances
- UL E78996 approved 

40 A
70 A
85 A
110 A

Description

These series of T-modules use standard recovery power rectifier diodes. The semiconductors are electrically isolated from the metal base, allowing common heatsink and compact assembly to be built. Applications include power supplies, battery charges, welders, motor controls and general industrial current rectification.

Major Ratings and Characteristics

| Parameters | T40HF | T70HF | T85HF | T110HF | Units | |
|------------------------|-------------|-------|--------|--------|-------------------|------------------|
| I _{F(AV)} | 40 | 70 | 85 | 110 | A | |
| I _{F(RMS)} | 63 | 110 | 134 | 173 | °C | |
| I _{FSM} | 50Hz | 570 | 1200 | 1700 | 2000 | A |
| | 60Hz | 600 | 1250 | 1800 | 2100 | A |
| I ² t | 50Hz | 1630 | 7100 | 14500 | 20500 | A ² s |
| | 60Hz | 1500 | 6450 | 13500 | 18600 | A ² s |
| I ² /t | 16300 | 70700 | 148700 | 204300 | A ² /s | |
| V _{RRM} range | 100 to 1200 | | | | V | |
| T _J | -40 to 150 | | | | °C | |

ELECTRICAL SPECIFICATIONS

Voltage Ratings

| Type number | Voltage Code | V _{RRM} , maximum repetitive peak reverse voltage V | V _{RSM} , maximum non-repetitive peak reverse voltage V | I _{RRM} max. T _J = @ 25°C μ A |
|---|--------------|---|---|---|
| T40HF.. T70HF.. T85HF.. T110HF.. | 10 | 100 | 150 | 100 |
| | 20 | 200 | 300 | |
| | 40 | 400 | 500 | |
| | 60 | 600 | 700 | |
| | 80 | 800 | 900 | |
| | 100 | 1000 | 1100 | |
| | 120 | 1200 | 1300 | |

Forward Conduction

| Parameters | T40HF | T70HF | T85HF | T110HF | Units | Conditions |
|---|-------|-------|--------|--------|-------------------|--|
| I _{F(AV)} Max. average fwd current @ Case temperature | 40 | 70 | 85 | 110 | A | 180° conduction, half sine wave |
| | 85 | 85 | 85 | 85 | °C | |
| I _{F(RMS)} Max. RMS forward current | 63 | 110 | 134 | 173 | A | |
| I _{FSM} Max. peak, one-cycle forward, non-repetitive surge current | 570 | 1200 | 1700 | 2000 | A | t = 10ms No voltage |
| | 600 | 1250 | 1800 | 2100 | | t = 8.3ms reapplied |
| | 480 | 1000 | 1450 | 1700 | | t = 10ms 100% V _{RRM} |
| | 500 | 1050 | 1500 | 1780 | | t = 8.3ms reapplied |
| I ² t Maximum I ² t for fusing | 1630 | 7100 | 14500 | 20500 | A ² s | t = 10ms No voltage |
| | 1500 | 6450 | 13500 | 18600 | | t = 8.3ms reapplied |
| | 1150 | 5000 | 10500 | 14500 | | t = 10ms 100% V _{RRM} |
| | 1050 | 4570 | 9600 | 13200 | | t = 8.3ms reapplied |
| I ² √t Maximum I ² √t for fusing | 16300 | 70700 | 148700 | 204300 | A ² √s | t = 0.1 to 10ms, no voltage reapplied |
| | | | | | | |
| | | | | | | |
| | | | | | | |
| V _{F(TO)1} Low level value of threshold voltage | 0.66 | 0.76 | 0.68 | 0.68 | V | (16.7% × π × I _{F(AV)}) < I < π × I _{F(AV)} , @ T _J max. |
| V _{F(TO)2} High level value of threshold voltage | 0.84 | 0.95 | 0.90 | 0.86 | V | (I > π × I _{F(AV)}), @ T _J max. |
| r _{f1} Low level value of forward slope resistance | 4.3 | 2.4 | 1.76 | 1.56 | mΩ | (16.7% × π × I _{F(AV)}) < I < π × I _{F(AV)} , @ T _J max. |
| r _{f2} High level value of forward slope resistance | 3.1 | 1.7 | 1.08 | 1.12 | mΩ | (I > π × I _{F(AV)}), @ T _J max. |
| V _{FM} Max. forward voltage drop | 1.30 | 1.35 | 1.27 | 1.35 | V | I _{FM} = π × I _{F(AV)} , T _J = 25°C, tp = 400 μs square pulse Av. power = V _{F(TO)} × I _{F(AV)} + r _f × (I _{F(RMS)}) ² |

Blocking

| Parameters | T40HF | T70HF | T85HF | T110HF | Units | Conditions |
|--|-------|-------|-------|--------|-------|---|
| I _{RRM} Max. peak reverse leakage current | 15 | 15 | 20 | 20 | mA | T _J = 150°C |
| V _{INS} RMS isolation voltage | 3500 | 3500 | 3500 | 3500 | V | 50Hz, circuit to base, all terminals shorted T _J = 25°C, t = 1s |

ΔR Conduction (per Junction)

(The following table shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC)

| Devices | Sinusoidal conduction @ T_J max. | | | | | Rectangular conduction @ T_J max. | | | | | Units |
|---------|------------------------------------|------|------|------|------|-------------------------------------|------|------|------|------|-------|
| | 180° | 120° | 90° | 60° | 30° | 180° | 120° | 90° | 60° | 30° | |
| T40HF | 0.12 | 0.14 | 0.18 | 0.27 | 0.46 | 0.09 | 0.15 | 0.20 | 0.28 | 0.46 | K/W |
| T70HF | 0.09 | 0.11 | 0.14 | 0.20 | 0.35 | 0.07 | 0.11 | 0.15 | 0.21 | 0.35 | |
| T85HF | 0.08 | 0.09 | 0.12 | 0.18 | 0.31 | 0.06 | 0.10 | 0.13 | 0.19 | 0.31 | |
| T110HF | 0.05 | 0.07 | 0.09 | 0.14 | 0.23 | 0.05 | 0.08 | 0.10 | 0.15 | 0.24 | |

Thermal and Mechanical Specifications

| Parameters | T40HF | T70HF | T85HF | T110HF | Units | Conditions |
|--|----------------|-------|-------|--------|-------|---|
| T_J Max. junction operating temperature range | -40 to 150 | | | | °C | |
| T_{stg} Max. storage temperature range | -40 to 150 | | | | °C | |
| R_{thJC} Max. thermal resistance, junction to case | 1.36 | 0.69 | 0.62 | 0.47 | K/W | DC operation, per junction |
| R_{thCS} Max. thermal resistance, case to heatsink | 0.2 | | | | K/W | Mounting surface smooth, flat and greased |
| T Mounting torque $\pm 10\%$ to heatsink terminals | 1.3 $\pm 10\%$ | | | | Nm | M3.5 mounting screws (2) non lubricated threads |
| | 3 $\pm 10\%$ | | | | | M5 screw terminals |
| wt Approximate weight | 54 | | | | g | See outline table |
| Case style | D-56 | | | | | T type |

(2) A mounting compound is recommended and the torque should be rechecked after a period of about 3 hours to allow for the spread of the compound

Ordering Information Table

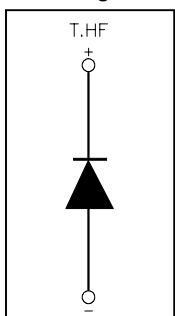
Device Code

| | | | |
|---|-----|----|-----|
| T | 110 | HF | 120 |
| ① | ② | ③ | ④ |

- 1 - Module type
- 2 - Current rating
- 3 - Circuit configuration **
- 4 - Voltage code : code x 10 = V_{RRM}

Circuit configuration **

T..HF



Outline Table

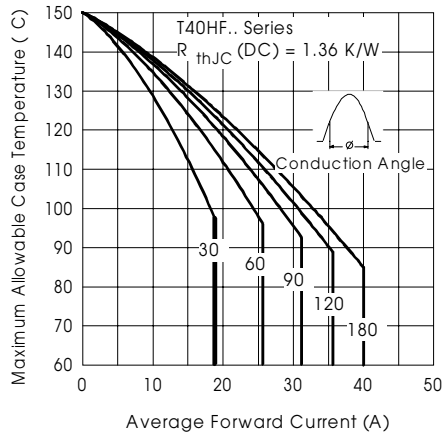
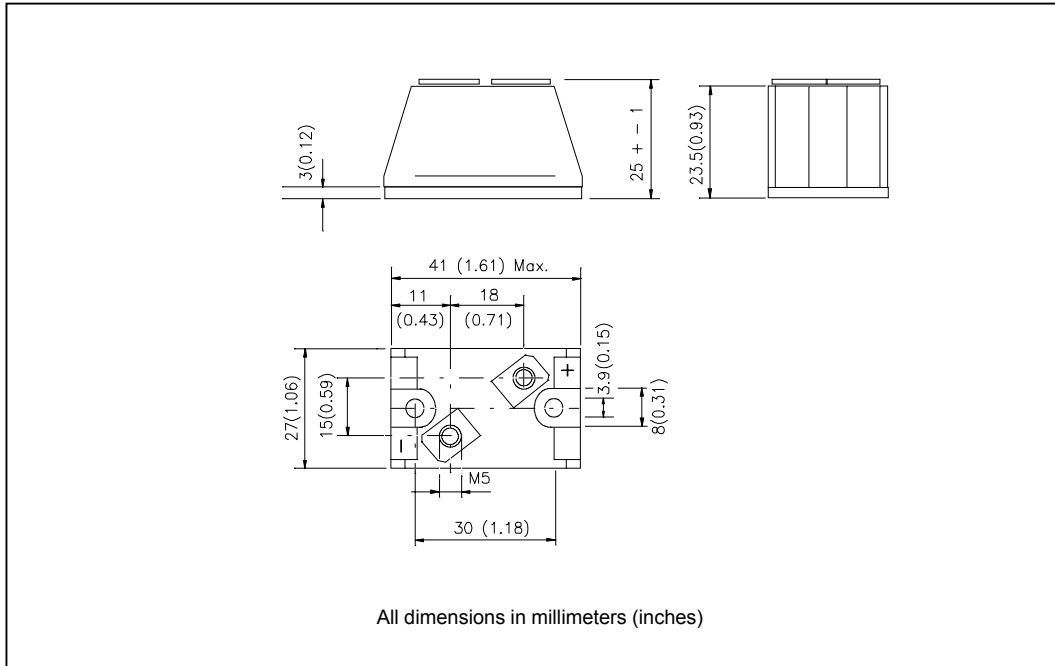


Fig. 1 - Current Ratings Characteristics

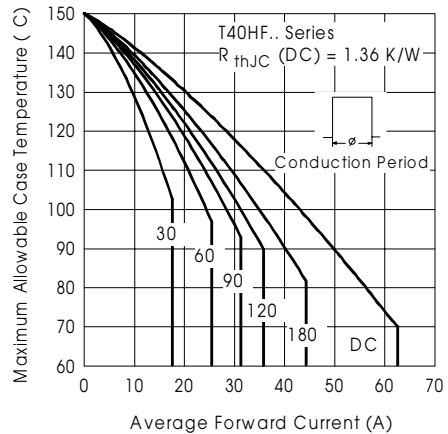


Fig. 2 - Current Ratings Characteristics

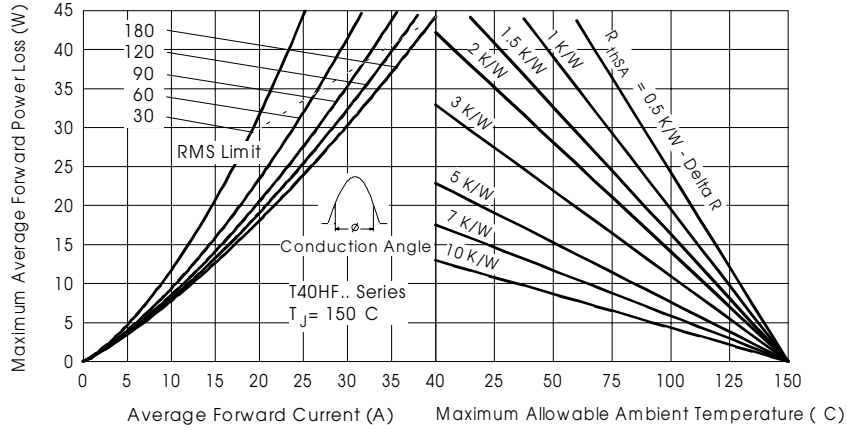


Fig. 3 - Forward Power Loss Characteristics

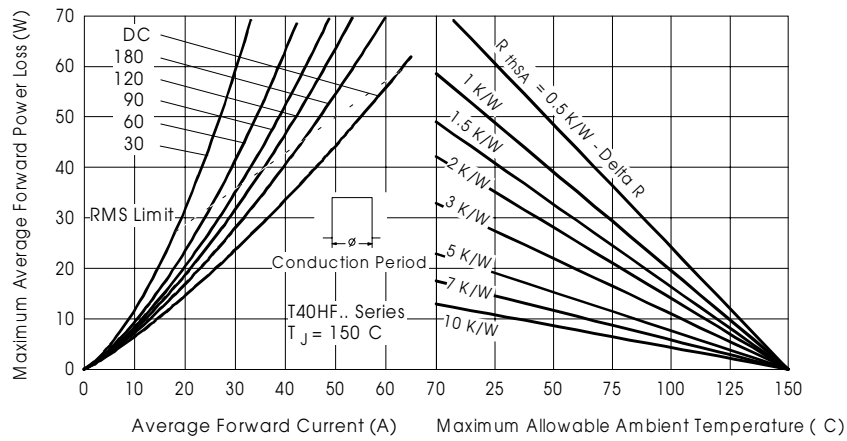


Fig. 4 - Forward Power Loss Characteristics

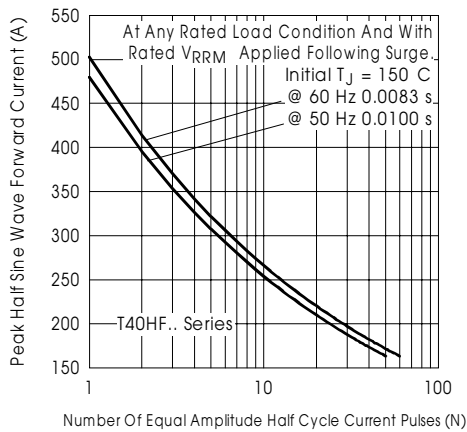


Fig. 5 - Maximum Non-Repetitive Surge Current

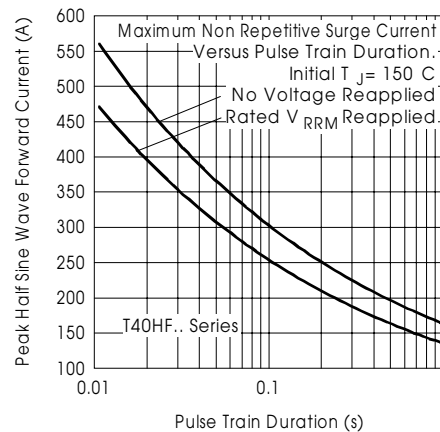


Fig. 6 - Maximum Non-Repetitive Surge Current

T..HF Series

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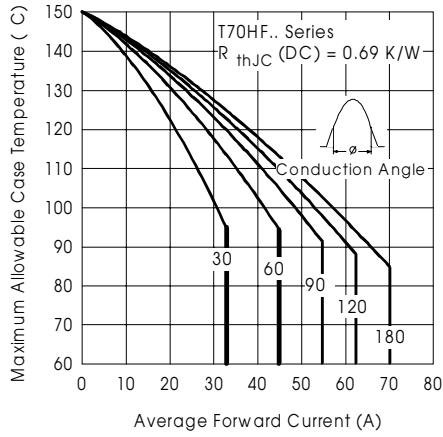


Fig. 7 - Current Ratings Characteristics

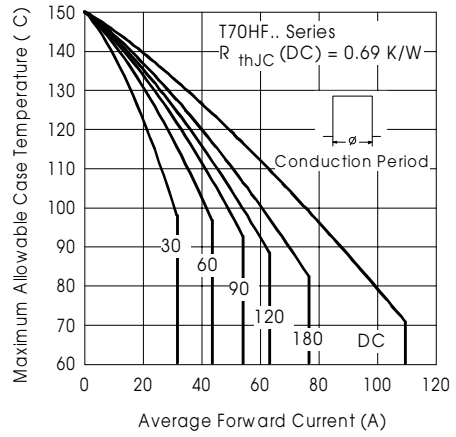


Fig. 8 - Current Ratings Characteristics

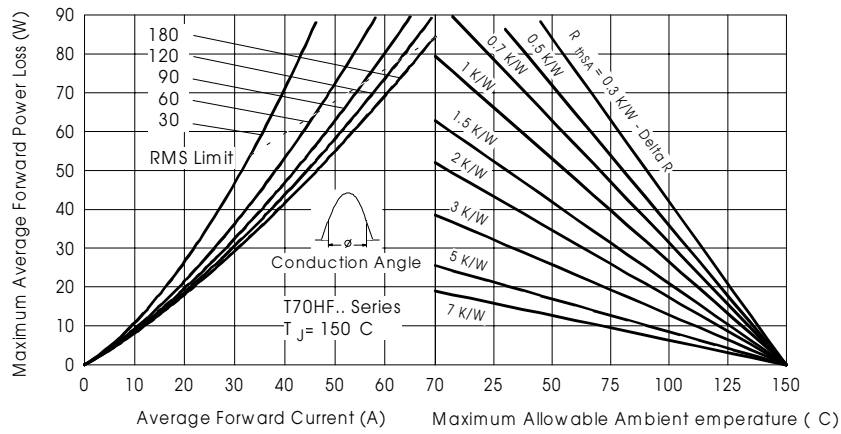


Fig. 9 - Forward Power Loss Characteristics

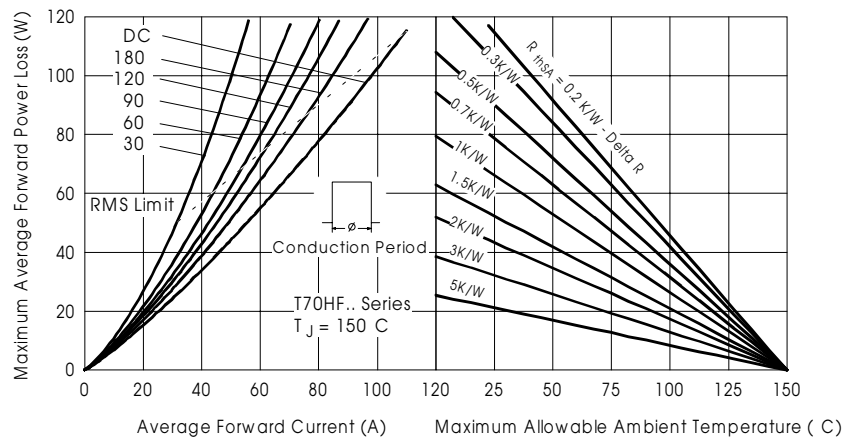


Fig. 10 - Forward Power Loss Characteristics

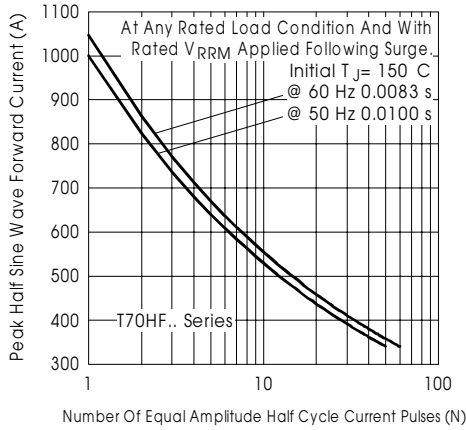


Fig. 11 - Maximum Non-Repetitive Surge Current

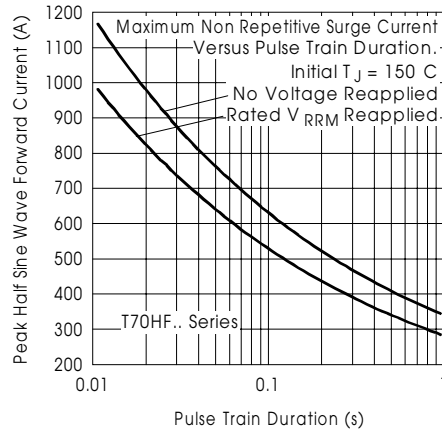


Fig. 12 - Maximum Non-Repetitive Surge Current

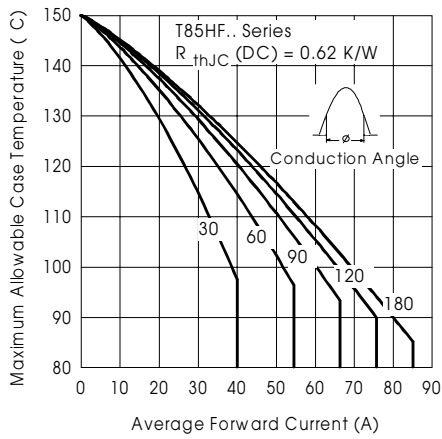


Fig. 13 - Current Ratings Characteristics

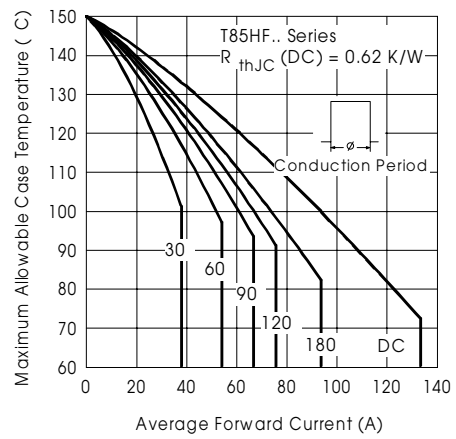


Fig. 14 - Current Ratings Characteristics

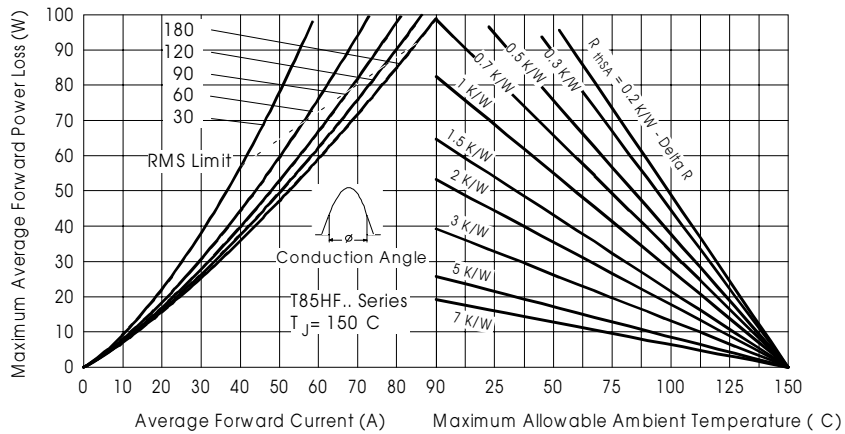


Fig. 15 - Forward Power Loss Characteristics

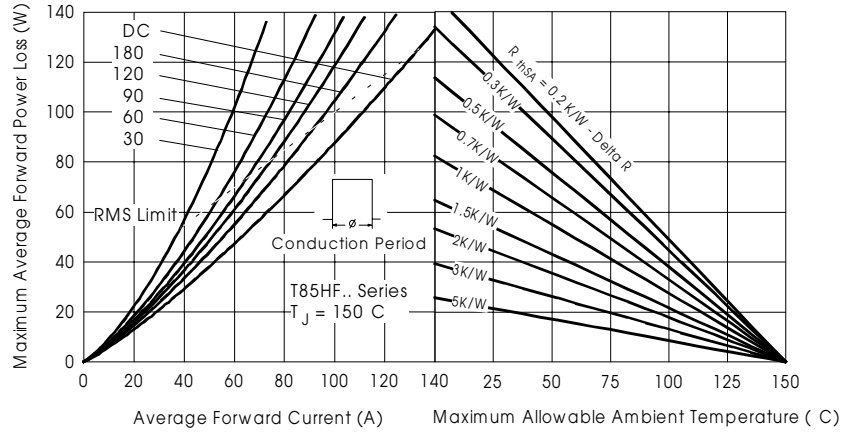


Fig. 16 - Forward Power Loss Characteristics

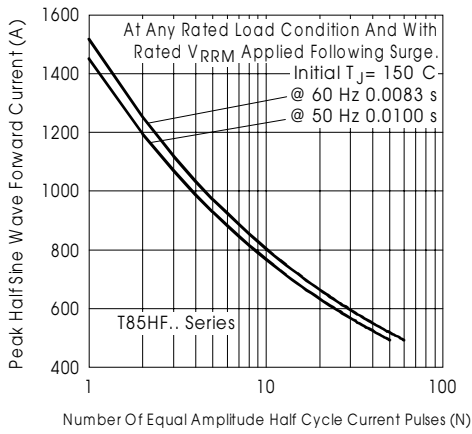


Fig. 17 - Maximum Non-Repetitive Surge Current

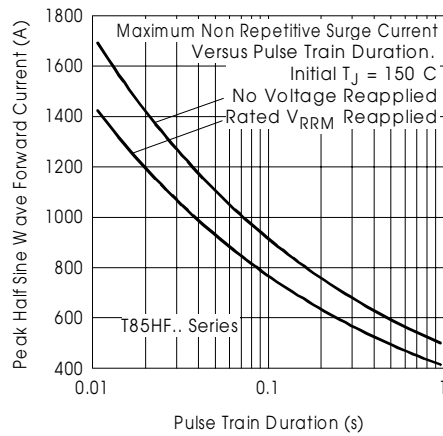


Fig. 18 - Maximum Non-Repetitive Surge Current

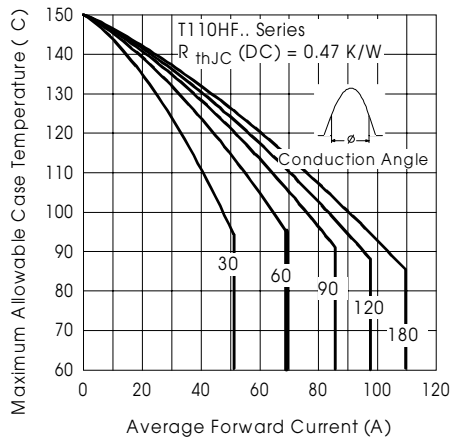


Fig. 19 - Current Ratings Characteristics

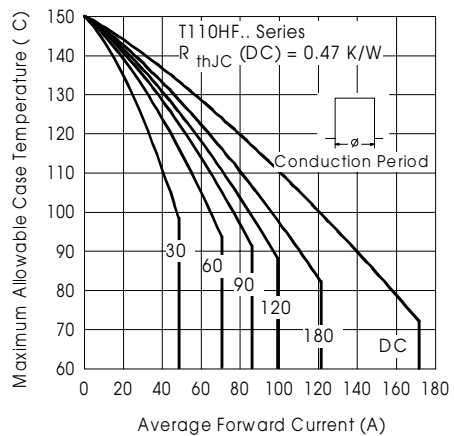


Fig. 20 - Current Ratings Characteristics

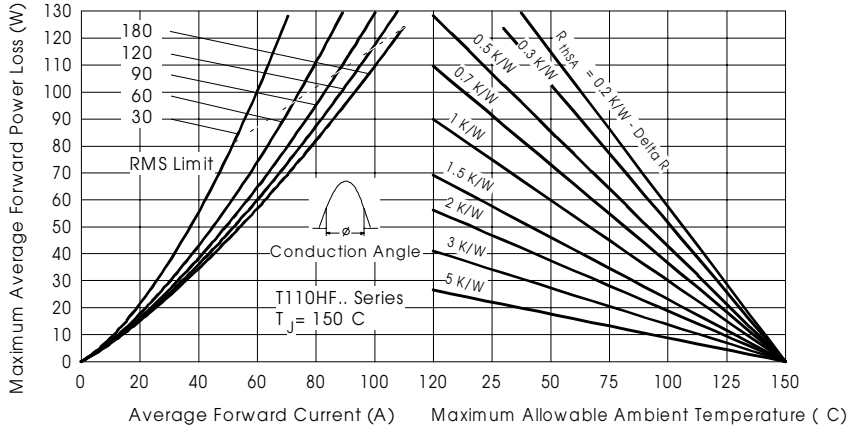


Fig. 21 - Forward Power Loss Characteristics

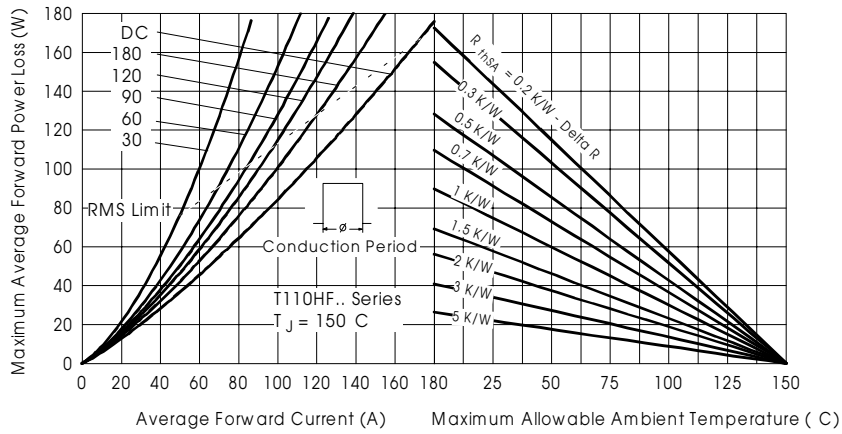


Fig. 22 - Forward Power Loss Characteristics

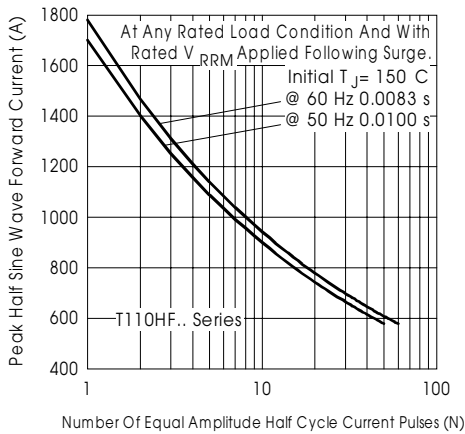


Fig. 23 - Maximum Non-Repetitive Surge Current

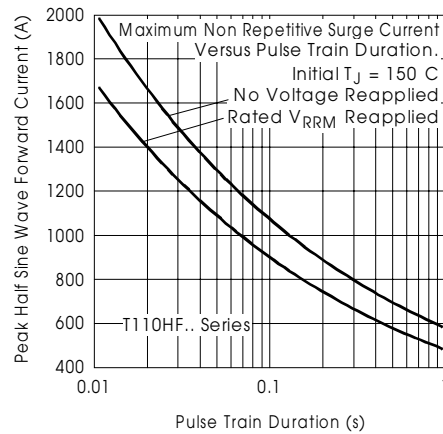


Fig. 24 - Maximum Non-Repetitive Surge Current

T..HF Series

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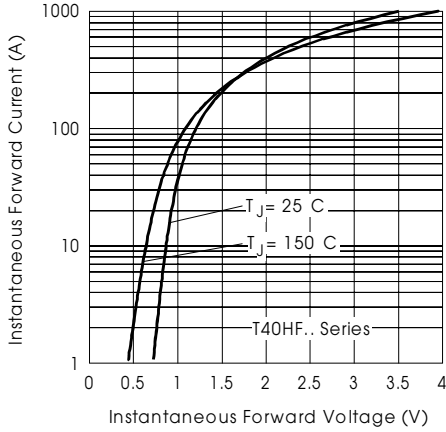


Fig. 25 - Forward Voltage Drop Characteristics

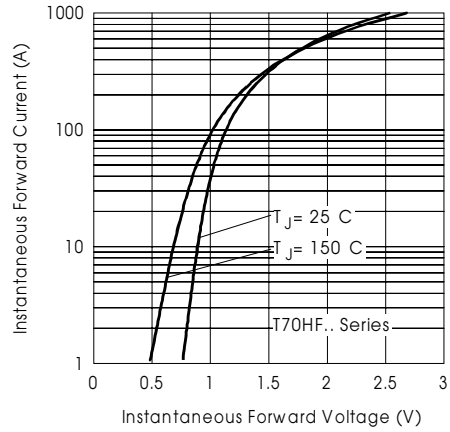


Fig. 26 - Forward Voltage Drop Characteristics

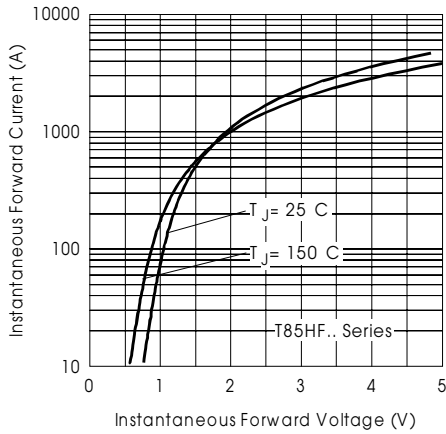


Fig. 27 - Forward Voltage Drop Characteristics

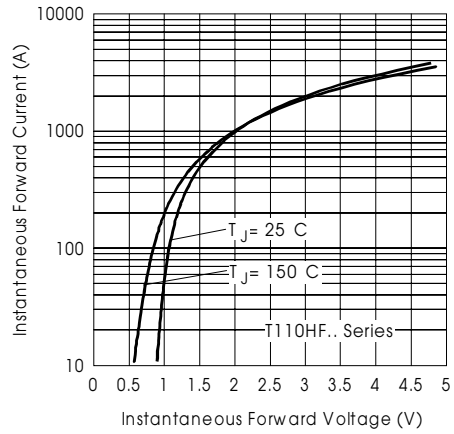


Fig. 28 - Forward Voltage Drop Characteristics

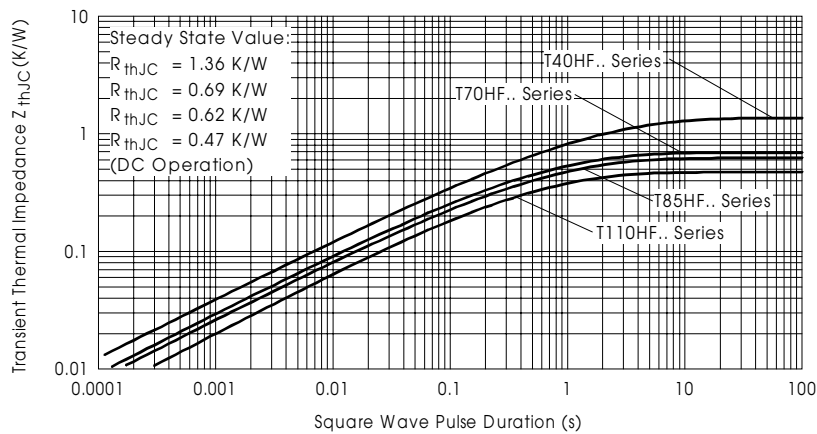


Fig. 29 - Thermal Impedance Z_{thJC} Characteristics

Data and specifications subject to change without notice.
This product has been designed and qualified for Industrial Level.
Qualification Standards can be found on IR's Web site.

International
IOR Rectifier

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